

FGA20S140P Shorted Anode™ IGBT

Features

- · High speed switching
- Low saturation voltage: V_{CE(sat)} =1.9V @ I_C = 20A
- · High input impedance
- · RoHS compliant

Applications

- Induction Heating and Microwave Oven
- · Soft Switching Applications



Using advanced Field Stop Trench and Shorted Anode technology, Fairchild's Shorted Anode™ Trench IGBTs offer superior conduction and switching performances, and easy parallel operation with exceptional avalanche capability. This device is designed for induction heating and microwave oven.

October 2012





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		Ratings	Units
V _{CES}	Collector to Emitter Voltage		1400	V
V _{GES}	Gate to Emitter Voltage		±25	V
I _C	Collector Current	@ T _C = 25°C	40	A
	Collector Current	@ T _C = 100 ^o C	20	A
I _{CM (1)}	Pulsed Collector Current		60	А
l _F	Diode Continuous Forward Current	@ T _C = 25°C	40	А
I _F	Diode Continuous Forward Current	@ T _C = 100 ^o C	20	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	272	W
	Maximum Power Dissipation	@ T _C = 100 ^o C	136	W
TJ	Operating Junction Temperature		-55 to +175	Oo
T _{stg}	Storage Temperature Range		-55 to +175	°C
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case		0.55	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient		40	°C/W

Notes: 1: Limited by Tjmax

Device Marking FGA20S140P		Device	Package			e Width	Qu	uantity
		FGA20S140P	TO-3PN			-		30
=lectric	al Char	acteristics of the		°C unless otherwise note				
Symbol		Parameter	-	Conditions	Min.	Тур.	Max.	Units
Off Charac	teristics							1
I _{CES}	Collector Cut-Off Current		V _{CE} = 1400,	V _{CE} = 1400, V _{GE} = 0V		-	1	mA
I _{GES}	G-E Leakage Current			$V_{GE} = V_{GES}, V_{CE} = 0V$		-	±500	nA
				-				
On Charac	1				4.5			
V _{GE(th)}	G-E Threshold Voltage		-	I_{C} = 20mA, V_{CE} = V_{GE}		6.0	7.5	V
		$I_{C} = 20A, V_{GE} = 15V$ $T_{C} = 25^{\circ}C$		₌ = 15V	-	1.9	2.4	V
V _{CE(sat)} Collector		o Emitter Saturation Voltage	e I _C = 20A, V _{GE}	I _C = 20A, V _{GE} = 15V,		2.1	-	V
				$T_{\rm C} = 125^{\circ}{\rm C}$				
			T _C = 20A, V _{GE} T _C = 175 ^o C	I _C = 20A, V _{GE} = 15V, T _C = 175 ^o C		2.2	-	V
V _{FM} Diode Forward Voltage		ward Voltage	I _F = 20A, T _C =	= 25°C	-	1.7	2.4	V
IT IVI		0 -	I _F = 20A, T _C =	= 175°C	-	2.1	-	V
Dynamic C C _{ies}	c Characteristics Input Capacitance Output Capacitance Reverse Transfer Capacitance			$V_{CE} = 30V, V_{GE} = 0V,$		1686	-	pF
C _{oes}			V _{CE} = 30V, V f = 1MHz			45	-	pF
C _{res}					-	32	-	pF
• • • •								
	Characcter					20		
t _{d(on)}	Turn-On D Rise Time				-	20		ns
t _r	Turn-Off D	alay Time			-	245 400	-	ns ns
t _{d(off)} t _f	Fall Time		V _{CC} = 600V, R _G = 10Ω, V ₀		-	130	- 169	ns
E _{on}		witching Loss	Resistive Loa	ad, $T_C = 25^{\circ}C$	_	0.76	-	mJ
E _{off}		witching Loss			_	0.56	0.73	mJ
E _{ts}	Total Swite		-	-		1.32	-	mJ
t _{d(on)}	Turn-On D	-			-	21	-	ns
t _r	Rise Time				-	301	-	ns
t _{d(off)}	Turn-Off D	elay Time	V _{CC} = 600V,	I _C = 20A,	-	420	-	ns
t _f	Fall Time		R _G = 10Ω, V ₀	_{GE} = 15V,	-	356	-	ns
Eon	Turn-On S	witching Loss	Resistive Loa	ad, T _C = 175 ^o C	-	0.95	-	mJ
E _{off}	Turn-Off S	witching Loss			-	1.39	-	mJ
E _{ts}	Total Swite	ching Loss			-	2.34	-	mJ
Qg	Total Gate	Charge			-	203.5	-	nC
Q _{ge}	Gate to Er	nitter Charge	V _{CE} = 600V, V _{GE} = 15V	I _C = 20A,	-	10.8	-	nC
Q _{gc}	Gate to Co	ollector Charge	$-v_{GE} = 15V$		-	84.6	-	nC



Typical Performance Characteristics

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1.5 3.0 4.5 6.0 Collector-Emitter Voltage, V_{CE} [V] 7.5



0

0.0



Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level



Figure 2. Typical Output Characteristics



Figure 4. Transfer Characteristics



Figure 6. Saturation Voltage vs. VGE



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Figure 15. Switching Loss VS. Gate Resistance



Figure 17. Turn off Switching SOA Characteristics











Figure 18. Forward Characteristics









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